

RBV5000 thru RBV5010

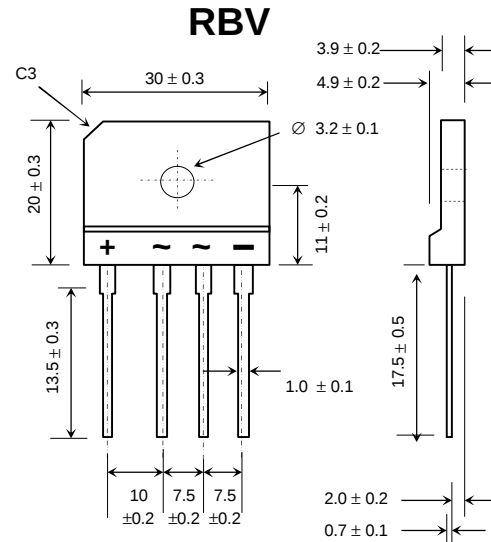
SINGLE-PHASE SILICON BRIDGE RECTIFIER
VOLTAGE RANGE 50 to 1000 Volts CURRENT 50 Amperes

FEATURES :

- * High current capability
- * High surge current capability
- * High reliability
- * Low reverse current
- * Low forward voltage drop
- * High case dielectric strength of 2000VDC
- * Ideal for printed circuit board
- * Very good heat dissipation

MECHANICAL DATA :

- * Case : Reliable low cost construction utilizing molded plastic technique
- * Epoxy : UL94V-O rate flame retardant
- * Terminals : Plated lead solderable per MIL-STD-202, Method 208 guaranteed
- * Polarity : Polarity symbols marked on case
- * Mounting position : Any
- * Weight : 8.17 grams (Approximaly)



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

RATING	SYMBOL	RBV 5000	RBV 5001	RBV 5002	RBV 5004	RBV 5006	RBV 5008	RBV 5010	UNIT
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Current $T_c = 55^\circ\text{C}$	$I_{F(AV)}$	50							A
Peak Forward Surge Current Single half sine wave Superimposed on rated load (JEDEC Method)	I_{FSM}	400							A
Current Squared Time at $t < 8.3$ ms.	I^2t	660							A^2S
Maximum Forward Voltage per Diode at $I_F = 25$ A	V_F	1.1							V
Maximum DC Reverse Current $T_a = 25^\circ\text{C}$ at Rated DC Blocking Voltage $T_a = 100^\circ\text{C}$	I_R	10							μA
	$I_{R(H)}$	200							μA
Typical Thermal Resistance (Note 1)	$R_{\theta JC}$	1.5							$^\circ\text{C/W}$
Operating Junction Temperature Range	T_J	10							$^\circ\text{C}$
Storage Temperature Range	T_{STG}	- 40 to + 150							$^\circ\text{C}$

Note :

1. Thermal Resistance from junction to case with units mounted on heatsink.



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RATING AND CHARACTERISTIC CURVES (RBV5000 - RBV5010)

FIG.1 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

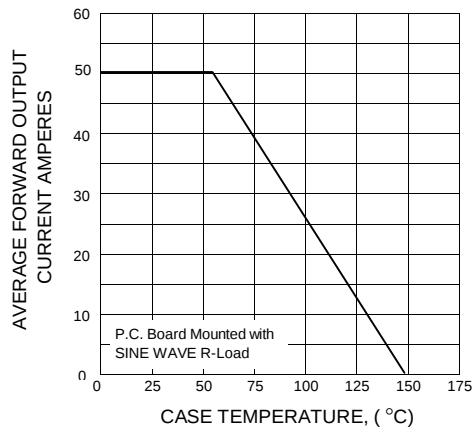


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

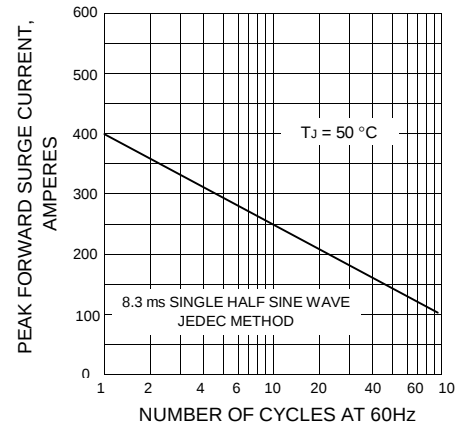


FIG.3 - TYPICAL FORWARD CHARACTERISTICS PER DIODE

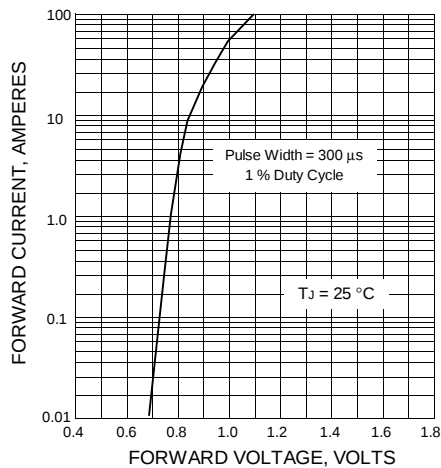


FIG.4 - TYPICAL REVERSE CHARACTERISTICS PER DIODE

